

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	29	(257/E29.188).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/27 12:27
L2	486	(257/E21.371).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/27 12:28
L3	27	(257/E21.541).CCLS.	US-PGPUB; USPAT; USOCR	OR	OFF	2006/02/27 12:28

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	566	heterojunction and planar and bipolar	USPAT	OR	OFF	2006/02/27 09:09
L2	82	1 and sic	USPAT	OR	OFF	2006/02/27 09:24
L3	1	"planar bipolar transistor" and "polysilicon contact"	USPAT	OR	OFF	2006/02/27 09:43
L4	0	"polysilicon base contact" and "planar contact"	USPAT	OR	OFF	2006/02/27 09:44
L5	0	"polysilicon base contact" and "planar contact"	USPAT	OR	OFF	2006/02/27 09:44
L6	107	"polysilicon base contact"	USPAT	OR	OFF	2006/02/27 09:44
L7	62	6 and planar\$	USPAT	OR	OFF	2006/02/27 10:28
L8	1	("5939738").PN.	USPAT; USOCR	OR	OFF	2006/02/27 10:30
L9	1	("5698871").PN.	USPAT; USOCR	OR	OFF	2006/02/27 10:55
L10	162	438/318	US-PGPUB; USPAT	OR	OFF	2006/02/27 11:22
L11	51	438/312.ccls. and planar	US-PGPUB; USPAT	OR	OFF	2006/02/27 11:22